

L Number	Hits	Search Text	DB	Time stamp
7	39	ALD with plasma	USPAT; US-PGPUB	2002/09/19 11:32
8	3655	goto.in.	USPAT; US-PGPUB	2002/09/19 10:57
9	218	goto.in. and plasma	USPAT; US-PGPUB	2002/09/19 10:57
10	0	(goto.in. and plasma) and ald	USPAT; US-PGPUB	2002/09/19 10:57
11	80	(goto.in. and plasma) and cvd	USPAT; US-PGPUB	2002/09/19 10:57
12	0	ALD and shield with perimeter with conductance	USPAT; US-PGPUB	2002/09/19 11:32
13	0	ALD and shield with periphery with conductance	USPAT; US-PGPUB	2002/09/19 11:32
14	5	ALD and shield with conductance	USPAT; US-PGPUB	2002/09/19 13:06
15	1	("4413022").PN.	USPAT; US-PGPUB	2002/09/19 14:23
16	5181	residence with time with pressure	USPAT; US-PGPUB	2002/09/19 14:24
17	3	(residence with time with pressure) and ALD	USPAT; US-PGPUB	2002/09/19 14:24
18	542	residence with time with pressure with depend\$4	USPAT; US-PGPUB	2002/09/19 14:25
19	20	residence with time with pressure with proportional	USPAT; US-PGPUB	2002/09/19 14:25
-	4	"999636"	USPAT; US-PGPUB	2002/09/17 13:05
-	12	"812352"	USPAT; US-PGPUB	2002/09/17 13:06
-	10	"812486"	USPAT; US-PGPUB	2002/09/17 13:06
-	43	"812285"	USPAT; US-PGPUB	2002/09/17 13:07
-	7	"854092"	USPAT; US-PGPUB	2002/09/17 13:21
-	4	"902080"	USPAT; US-PGPUB	2002/09/17 15:31
-	724	atomic adj layer adj (deposition epitaxy)	USPAT; US-PGPUB	2002/09/17 15:40
-	3696	ale ald peald peald	USPAT; US-PGPUB	2002/09/17 16:39
-	3916	(ale ald peald peald) or (atomic adj layer adj (deposition epitaxy))	USPAT; US-PGPUB	2002/09/17 16:13
-	232	((ale ald peald peald) or (atomic adj layer adj (deposition epitaxy))) and flux	USPAT; US-PGPUB	2002/09/17 16:15
-	18	((ale ald peald peald) or (atomic adj layer adj (deposition epitaxy))) and flux) and conductance	USPAT; US-PGPUB	2002/09/17 16:31
-	3	((ale ald peald peald) or (atomic adj layer adj (deposition epitaxy))) and conductance with exit	USPAT; US-PGPUB	2002/09/17 16:37
-	1	((ale ald peald peald) or (atomic adj layer adj (deposition epitaxy))) and conductance with exhaust	USPAT; US-PGPUB	2002/09/17 16:38
-	3810	ale ald peald peale	USPAT; US-PGPUB	2002/09/17 16:39
-	4030	(atomic adj layer adj (deposition epitaxy)) or (ale ald peald peale)	USPAT; US-PGPUB	2002/09/17 16:54
-	123	((atomic adj layer adj (deposition epitaxy)) or (ale ald peald peale)) and conductance	USPAT; US-PGPUB	2002/09/17 16:40
-	27	((atomic adj layer adj (deposition epitaxy)) or (ale ald peald peale)) and (conduct\$6 or restrict\$6) with (exit exhaust leave)	USPAT; US-PGPUB	2002/09/17 16:46

-	9	((atomic adj layer adj (deposition epitaxy)) or (ale ald peald peale)) and (conductance with (vary change changing varying alter altering))	USPAT; US-PGPUB	2002/09/17 16:50
-	3	((atomic adj layer adj (deposition epitaxy)) or (ale ald peald peale)) and open with exhaust with purge	USPAT; US-PGPUB	2002/09/17 17:15
-	2	"979465"	USPAT; US-PGPUB	2002/09/17 17:16
-	2889	(118/715,720,721,722,723R,723VE).CCLS.	USPAT; US-PGPUB	2002/09/18 13:04
-	51490	?3CVD or (chemical adj vapor adj deposition)	USPAT; US-PGPUB	2002/09/18 14:03
-	116	(?3CVD or (chemical adj vapor adj deposition)) and conductance with (exhaust exit)	USPAT; US-PGPUB	2002/09/18 13:06
-	4	(?3CVD or (chemical adj vapor adj deposition)) and conductance with (exhaust exit) with (vary varying change changing)	USPAT; US-PGPUB	2002/09/18 13:11
-	167	conductance with (exhaust exit) with (vary varying change changing valve)	USPAT; US-PGPUB	2002/09/18 13:11
-	35	conductance with (exhaust exit) with (vary varying change changing)	USPAT; US-PGPUB	2002/09/18 13:12
-	199	conductance with (exhaust exit) with (vary varying change changing varied changed valve adjusted adjust adjusting)	USPAT; US-PGPUB	2002/09/18 13:24
-	2032	427/457,458,466,470,523,526,527,529,530,528,532,533,535.ccls.	USPAT; US-PGPUB	2002/09/18 13:16
-	411	(427/561,562,564).CCLS.	USPAT; US-PGPUB	2002/09/18 13:16
-	1692	(427/569,570,576,585).CCLS.	USPAT; US-PGPUB	2002/09/18 13:16
-	2396	(427/248.1,255.11,255.15,255.19,255.21,255.7).CCLS.)	USPAT; US-PGPUB	2002/09/18 13:16
-	8199	((118/715,720,721,722,723R,723VE).CCLS.) 427/457,458,466,470,523,526,527,529,530,528,532,533,535.ccls. ((427/561,562,564).CCLS.) ((427/569,570,576,585).CCLS.) ((427/248.1,255.11,255.15,255.19,255.21,255.7).CCLS.)	USPAT; US-PGPUB	2002/09/18 13:16
-	41	((118/715,720,721,722,723R,723VE).CCLS.) 427/457,458,466,470,523,526,527,529,530,528,532,533,535.ccls. ((427/561,562,564).CCLS.) ((427/569,570,576,585).CCLS.) ((427/248.1,255.11,255.15,255.19,255.21,255.7).CCLS.)	USPAT; US-PGPUB	2002/09/18 13:17
-	0	(conductance with (exhaust exit) with (vary varying change changing varied changed valve adjusted adjust adjusting)) and (atomic adj layer adj (epitax\$3 or deposition))	USPAT; US-PGPUB	2002/09/18 13:48
-	21	(conductance with (exhaust exit) with (vary varying change changing varied changed valve adjusted adjust adjusting)) and purge	USPAT; US-PGPUB	2002/09/18 13:48
-	1	(conductance with (exhaust exit) with (vary varying change changing varied changed valve adjusted adjust adjusting)) with purge	USPAT; US-PGPUB	2002/09/18 13:26
-	1346	(atomic adj layer adj (epitax\$3 or deposition)) or ALD	USPAT; US-PGPUB	2002/09/18 13:49
-	807	((atomic adj layer adj (epitax\$3 or deposition)) or ALD) and pressure	USPAT; US-PGPUB	2002/09/18 13:49
-	154	((atomic adj layer adj (epitax\$3 or deposition)) or ALD) and purge	USPAT; US-PGPUB	2002/09/18 13:49
-	30	((atomic adj layer adj (epitax\$3 or deposition)) or ALD) and purge with pressure	USPAT; US-PGPUB	2002/09/18 14:26
-	0	((atomic adj layer adj (epitax\$3 or deposition)) or ALD) and depsotion with rate with pressure	USPAT; US-PGPUB	2002/09/18 13:52

-	39	((atomic adj layer adj (epitax\$3 or deposition)) or ALD) and deposition with rate with pressure	USPAT; US-PGPUB	2002/09/18 13:54
-	825	(digital sequen\$7) with (chemical adj vapor adj deposition)	USPAT; US-PGPUB	2002/09/18 14:04
-	0	(digital sequen\$7) with (chemical adj vapor adj deposition) and (conductance with (exhaust exit) with (vary varying change changing valve))	USPAT; US-PGPUB	2002/09/18 14:04
-	8	(digital sequen\$7) with (chemical adj vapor adj deposition) and conductance with (exhaust exit)	USPAT; US-PGPUB	2002/09/18 14:05
-	3	((atomic adj layer adj (epitax\$3 or deposition)) or ALD) and (flux conductance) with deposition with rate	USPAT; US-PGPUB	2002/09/18 15:05
-	1	("5972430").PN.	USPAT; US-PGPUB	2002/09/18 15:05